

Medium-Power Complementary Silicon Transistors

... for use as output devices in complementary general purpose amplifier applications.

- High DC Current Gain —
 $h_{FE} = 4000$ (Typ) @ $I_C = 5.0$ Adc
- Monolithic Construction with Built-in Base-Emitter Shunt Resistors

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Collector-Emitter Voltage	V_{CEO}	80	Vdc
Collector-Base Voltage	V_{CB}	80	Vdc
Emitter-Base Voltage	V_{EB}	5.0	Vdc
Collector Current	I_C	10	Adc
Base Current	I_B	0.2	Adc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	150 0.857	Watts W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-55 to +200	$^\circ\text{C}$

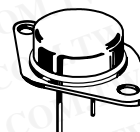
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	θ_{JC}	1.17	$^\circ\text{C/W}$

PNP
MJ2501
NPN
MJ3001

ON Semiconductor Preferred Devices

10 AMPERE
DARLINGTON
POWER TRANSISTOR
COMPLEMENTARY
SILICON
80 VOLTS
150 WATTS



CASE 1-07
TO-204AA
(TO-3)

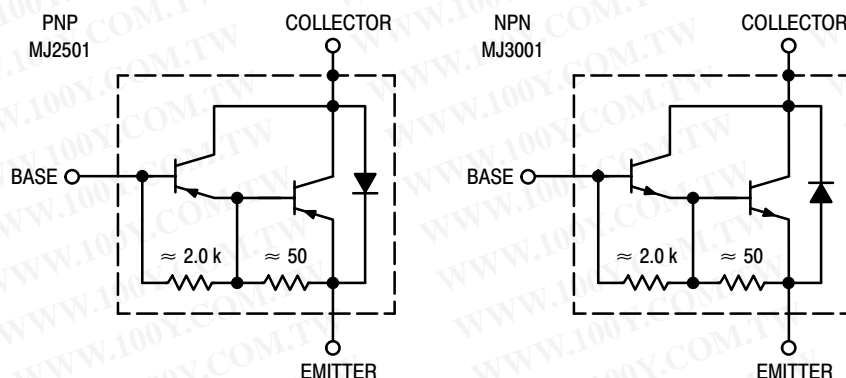


Figure 1. Darlington Circuit Schematic

Preferred devices are ON Semiconductor recommended choices for future use and best overall value.

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MJ2501 MJ3001

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Collector Emitter Breakdown Voltage ⁽¹⁾ ($I_C = 100\text{ mAdc}$, $I_B = 0$)	$V_{(BR)CEO}$	80	—	Vdc
Collector–Emitter Leakage Current ($V_{EB} = 80\text{ Vdc}$, $R_{BE} = 1.0\text{ k ohm}$) ($V_{EB} = 80\text{ Vdc}$, $R_{BE} = 1.0\text{ k ohm}$, $T_C = 150^\circ\text{C}$)	I_{CER}	— —	1.0 5.0	mAdc
Emitter Cutoff Current ($V_{BE} = 5.0\text{ Vdc}$, $I_C = 0$)	I_{EBO}	—	2.0	mAdc
Collector Emitter Leakage Current ($V_{CE} = 40\text{ Vdc}$, $I_B = 0$)	I_{CEO}	—	1.0	mAdc

ON CHARACTERISTICS⁽¹⁾

DC Current Gain ($I_C = 5.0\text{ Adc}$, $V_{CE} = 3.0\text{ Vdc}$)	h_{FE}	1000	—	—
Collector–Emitter Saturation Voltage ($I_C = 5.0\text{ Adc}$, $I_B = 20\text{ mAdc}$) ($I_C = 10\text{ Adc}$, $I_B = 50\text{ mAdc}$)	$V_{CE(sat)}$	— —	2.0 4.0	Vdc
Base Emitter Voltage ($I_C = 5.0\text{ Adc}$, $V_{CE} = 3.0\text{ Vdc}$)	$V_{BE(on)}$	—	3.0	Vdc

⁽¹⁾Pulse Test: Pulse Width $\leq 300\text{ }\mu\text{s}$, Duty Cycle $\leq 2.0\%$.

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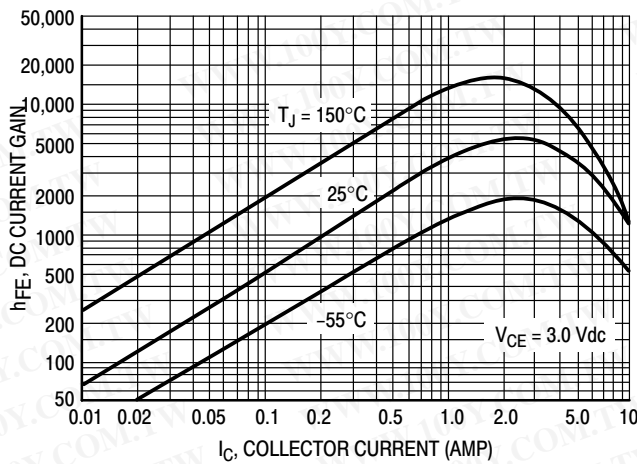


Figure 2. DC Current Gain

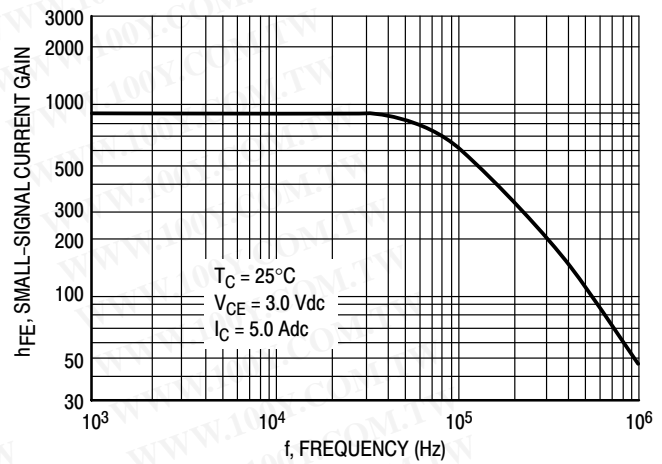


Figure 3. Small-Signal Current Gain

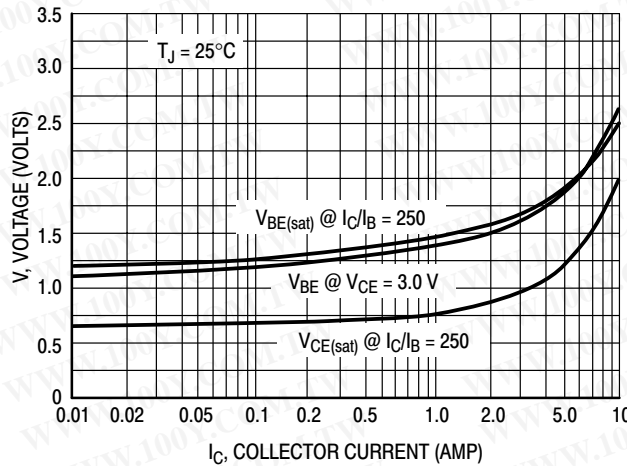


Figure 4. "On" Voltages

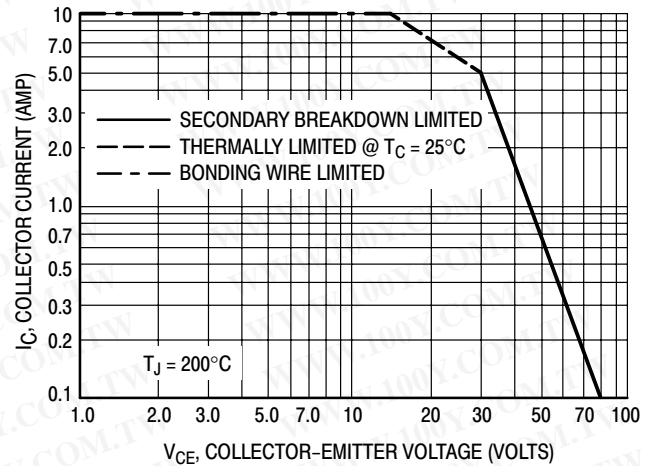


Figure 5. DC Safe Operating Area

There are two limitations on the power handling ability of a transistor: junction temperature and secondary breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; e.g., the transistor must not be subjected to greater dissipation than the curves indicate.

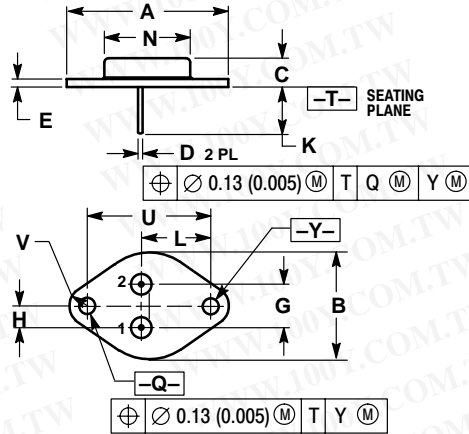
At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by secondary breakdown.

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MJ2501 MJ3001

PACKAGE DIMENSIONS

CASE 1-07 TO-204AA (TO-3) ISSUE Z




- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.550	REF	39.37	REF
B	---	1.050	---	26.67
C	0.250	0.335	6.35	8.51
D	0.038	0.043	0.97	1.09
E	0.055	0.070	1.40	1.77
G	0.430	BSC	10.92	BSC
H	0.215	BSC	5.46	BSC
K	0.440	0.480	11.18	12.19
L	0.665	BSC	16.89	BSC
N	---	0.830	---	21.08
Q	0.151	0.165	3.84	4.19
U	1.187	BSC	30.15	BSC
V	0.131	0.188	3.33	4.77

STYLE 1:
PIN 1. BASE
2. EMITTER
CASE: COLLECTOR

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